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Inclosure Material:

Metal

Overall Length:

1.500 inches

Overall Height:

0.450 inches

Overall Width:

1.000 inches

End Application:

Yellowstone class ad-41; emory s. Land class as; ticonderoga class cg (47)

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

5.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

50.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter

Special Features:

Weapon system essential; junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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